Transistor

Small switching (60V, 2A) 2SK3065

Features

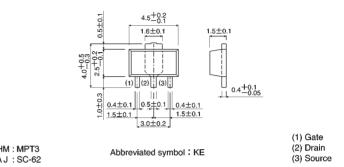
- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Low-voltage drive (2.5V) that is perfect for portable devices.
- 4) Easily designed drive circuits.
- 5) Easy to use in parallel.
- 6) Excellent resistance to damage from static electricity.

Structure

Silicon N-channel MOSFET

ROHM : MPT3 EIAJ : SC-62

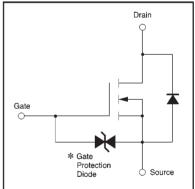
External dimensions (Units: mm)



• Absolute maximum ratings (Ta = 25° C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		VDSS	30	V
Gate-source voltage		Vgss	±20	V
	Continuous	lo	2	А
Drain current	Pulsed	DP*1	8	А
Reverse drain current	Continuous	I DR	2	А
	Pulsed	DRP*1	8	А
Total power dissipation	on(Tc=25°C)	Po	0.5 2*2	
Channel temperature		Tch	150	Ĵ
Storage temperature	Storage temperature		-55~+150	°C

Equivalent circuit



*1 Pw≦10 µs, Duty cycle≦1%

*2 When mounted on a 40 imes 40 imes 0.7 mm alumina board.

* A protection diode has been built in between the gate and the source to protect against static electricity when the product is in use. Use the protection circuit when rated voltages are exceeded.

•Electrical characteristics (Ta = 25° C)

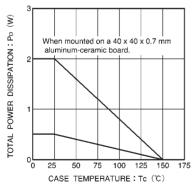
Parameter	Symbol	Min.	Тур.	Max.	Unit	Test Conditions
Gate-source leakage	I _{GSS}	-	-	±10	μA	$V_{GS}=\pm 20V, V_{DS}=0V$
Drain-source breakdown voltage	V(BR)DSS	60	_		V	ID=1mA, VGS=0V
Zero gate voltage drain current	loss	_	_	10	μA	VDS=60V, VGS=0V
Gate threshold voltage	VGS (th)	0.8	_	1.5	V	V _{DS} =10V, I _D =1mA
Static drain-source on-state	RDS (on)	-	0.25	0.32	Ω	ID=1A, VGS=4V
resistance	RDS (on)	_	0.35	0.45	Ω	ID=1A, VGS=2.5V
Forward transfer admittance	Y _{fs} *	1.5	_	-	S	ID=1A, VDS=10V
Input capacitance	Ciss	-	160	-	pF	V _{DS} =10V
Output capacitance	Coss	-	85	_	pF	V _{GS} =0V
Reverse transfer capacitance	Crss	_	25	_	pF	f=1MHz
Turn-on delay time	td (on)	_	20	_	ns	I□=1A, V□□≑30V
Rise time	tr	_	50	-	ns	V _{GS} =4V
Turn-off delay time	td (off)	_	120	-	ns	RL=30Ω
Fall time	tr	_	70	_	ns	Rg=10Ω

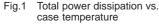
* $Pw \leq 300 \ \mu s$, Duty cycle $\leq 1\%$

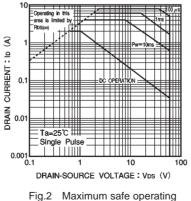
Packaging specifications

Туре	Package	Taping
	Code	T100
	Basic ordering unit (pieces)	1000
2SK306	0	

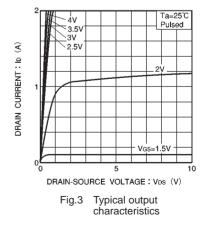
Electrical characteristic curves

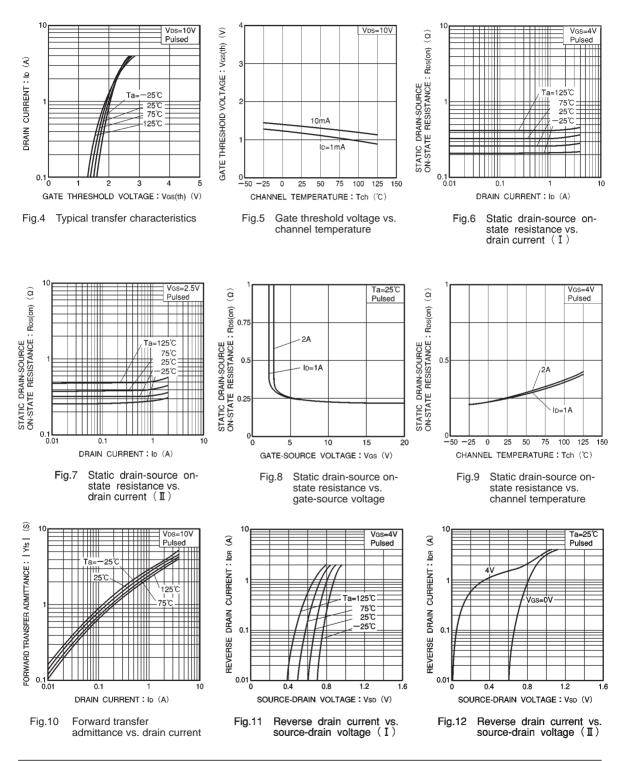






rig.2 Maximum safe operating area





Transistor

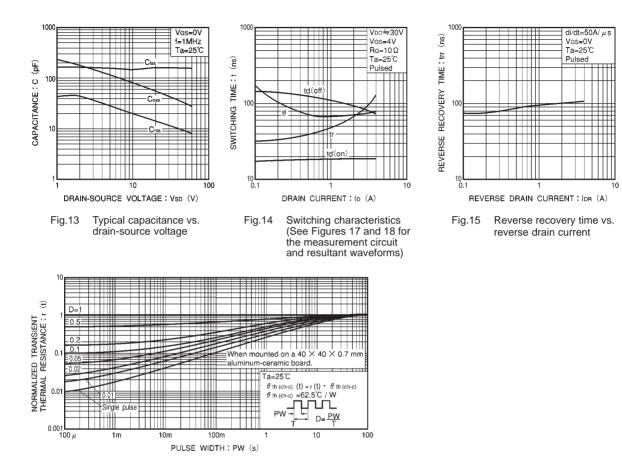


Fig.16 Normarized transient thermal resistance vs. pulse width

Switching characteristics measurement circuit

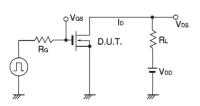


Fig17 Switching time measurement circuit

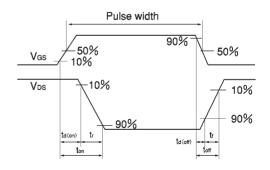


Fig18 Switching time waveforms